

## **isc Silicon NPN Power Transistor**

## 2SC4383

### DESCRIPTION

- Mold package that does not require an insulating board or insulation bushing
- High Speed Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

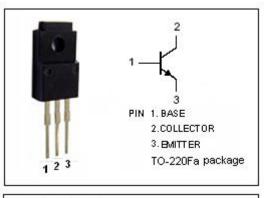
### **APPLICATIONS**

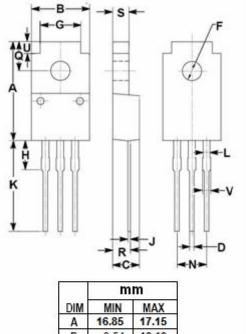
• This transistor is ideal for use in 50KHz class switching regulators.

SYMBOL	PARAMETER	VALUE	UNIT
Vсво	Collector-Base Voltage	200	V
V <sub>CEO</sub>	Collector-Emitter Voltage	180	V
$V_{\text{EBO}}$	Emitter-Base Voltage	7	V
lc	Collector Current-Continuous	8	A
I <sub>CM</sub>	Collector Current-Peak	16	A
I <sub>B</sub>	Base Current-Continuous	3	A
Pc	Collector Power Dissipation @T <sub>a</sub> =25℃	2.5	
	Collector Power Dissipation @T <sub>C</sub> =25℃	40	W
Tj	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C

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### ABSOLUTE MAXIMUM RATINGS (Ta=25°C)





DIM	MIIN	MAA
A	16.85	17.15
В	9.54	10.10
C	4.35	4.65
D	0.75	0.90
F	3.20	3.40
G	6.90	7.20
H	5.15	5.45
J	0.45	0.75
K	13.35	13.65
L	1.10	1.30
N	4.98	5.18
Q	4.85	5.15
R	2.55	3.25
S	2.70	2.90
U	1.75	2.05
V	1.30	1.50

isc website: <u>www.iscsemi.com</u>



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### **ELECTRICAL CHARACTERISTICS**

#### Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 25mA; I <sub>B</sub> = 0	180			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> =3A; I <sub>B</sub> = 300mA			1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> =3A; I <sub>B</sub> = 300mA			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> =200V; I <sub>E</sub> = 0			10	μ Α
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			10	μA
hfe	DC Current Gain	Ic= 3A; Vce= 4V	30			
Switching T	imes		I	1	1	1
ton	Turn-on Time				2	μS
ts	Storage Time	I <sub>C</sub> =3A; I <sub>B1</sub> = 0.3A; I <sub>B2</sub> = -0.3A;			1	μS
t <sub>f</sub>	Fall Time				1	μ <b>S</b>

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